

TN5415A Datasheet

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DiGi Electronics Part Number	TN5415A-DG
Manufacturer	onsemi
Manufacturer Product Number	TN5415A
Description	TRANS PNP 200V 0.1A TO226-3
Detailed Description	Bipolar (BJT) Transistor PNP 200 V 100 mA 1 W Through Hole TO-226-3



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Purchase and inquiry

Manufacturer Product Number:

TN5415A

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

200 V

Current - Collector Cutoff (Max):

50 μ A

Power - Max:

1 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-226-3, TO-92-3 (TO-226AA)

Base Product Number:

TN5415

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Vce Saturation (Max) @ Ib, Ic:

2.5V @ 5mA, 50mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

30 @ 50mA, 10V

Frequency - Transition:

-

Mounting Type:

Through Hole

Supplier Device Package:

TO-226-3

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

REACH Unaffected

HTSUS:

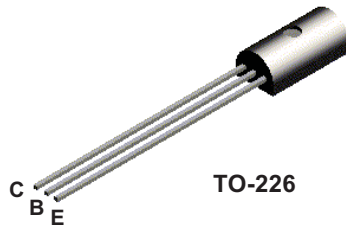
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**Discrete POWER & Signal
Technologies**

TN5415A

TN5415A



PNP High Voltage Amplifier

This device is designed for use as high voltage drivers requiring collector currents to 100 mA. Sourced from Process 76. See MPSA92 for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	200	V
V_{CBO}	Collector-Base Voltage	200	V
V_{EBO}	Emitter-Base Voltage	4.0	V
I_C	Collector Current - Continuous	100	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		TN5415A	
P_D	Total Device Dissipation Derate above 25°C	1.0	W
		8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	50	°C/W

PNP High Voltage Amplifier

(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 50 \text{ mA}, I_B = 0$	200		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 100 \text{ }\mu\text{A}, I_E = 0$	200		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 100 \text{ }\mu\text{A}, I_C = 0$	4.0		V
I_{CBO}	Collector Cutoff Current	$V_{CB} = 175 \text{ V}$		50	μA
I_{CEX}	Collector Cutoff Current	$V_{CE} = 200 \text{ V}, V_{BE} = 1.5 \text{ V (rev)}$		50	μA
I_{CEO}	Collector Cutoff Current	$V_{CE} = 150 \text{ V}$		50	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = 4.0 \text{ V}, I_C = 0$		20	μA

ON CHARACTERISTICS*

h_{FE}	DC Current Gain	$V_{CE} = 10 \text{ V}, I_C = 50 \text{ mA}$	30	150	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		2.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}$		1.5	V

SMALL SIGNAL CHARACTERISTICS

C_{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, f = 1.0 \text{ MHz}$		15	pF
C_{ib}	Input Capacitance	$V_{EB} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$		75	pF
h_{fe}	Small-Signal Current Gain	$I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V},$ $f = 5.0 \text{ MHz}$ $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V},$ $f = 1.0 \text{ kHz}$	3.0 25		
$R_{\theta(hie)}$	Input Resistance	$V_{CE} = 10 \text{ V}, I_C = 5.0 \text{ mA}$		300	Ω
IS / _b	Safe Operating Area	$V_{CE} = 100 \text{ V}, t = 100 \text{ mS}$	100		mA

*Pulse Test: Pulse Width $\leq 300 \text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$

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